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VI-Semester
MID SEMESTER EXAMINATION

Roll. No.----B.Tech (EP) March-2019

## **EP306 Microwave Engineering**

Time: 1:30 Hours Max. Marks:30

Note: Answer all question:

Assume suitable missing data, if any

- Define a microwave junction. How can it be described by scattering matrix? Derive the scattering matrix relation between the input and output of n×n junction starting with an analogy of a transmission line junction.
- 2. A signal of power 32 mW is fed into one of the collinear ports of a lossless H- plane Tee. Determine the powers in the remaining ports when other ports are terminated by means of matched loads. (5)
- 3. Explain the action of isolator and gyrator using ferrite. Mention their typical application. (5)
- 4. Explain the operation, construction and application of TRAPATT diode. (5)
- 5. An IMPATT diode has a drift length of  $2 \mu m$ . Determine the operating frequency of the IMPATT diode if the drift velocity for Si is  $10^7$  cm/sec. (5)
- 6. Write short note of any two on following: (5)
  (a)Avalanche transit time (b) waveguide Irises and (c) Gunn diode.

END